Influence of Ni (II) Oxime Complex Coupled with the Combination of Diverse Sized ZnO Nanoparticles on Photovoltaic Performance

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ABSTRACT

The one side selective synthesis of quinoline carboxylic acid oxime complex was carried out successfully. The as-prepared quinoline carboxylic acid oxime complex was complexed with nickel (II) salts to form nickel (II) oxime complex. These complexes were further adsorbed onto ZnO films containing ZnO nanoparticles of various sizes. ZnO films containing a diverse proportion of ZnO nanoparticles were investigated to enhance the photovoltaic efficiency of the dye-sensitized solar cell. The as-synthesized complex was characterized by scanning electron microscopy (SEM), Ultra violet visible spectroscopy (UV-vis), Fourier Transform Infrared Spectroscopy (FT-IR) spectroscopy, 1H-Nuclear Magnetic resonance spectroscopy (1HNMR), Liquid chromatography coupled with mass spectrometry (LC-MR), Brunauer–Emmett–Teller (BET), and Attenuated total reflection Infra-red spectroscopy (ATR-IR). The combination of large and small ZnO nanoparticles has significantly improves the photovoltaic efficiency. The optimum mixing ratio for the best performance (0.127%) of a dye-sensitized solar cell is achieved by mixing the small: large ZnO particles in a ratio 60:40. The increased efficiency is due to the harvesting of light caused by scattering effect from larger sized ZnO particles. The ZnO layer consisting of smaller particles which are very next to the ZnO bigger particles makes a good electronic contact between film electrode and the Indium-doped tin oxide glass substrate resulting in the increases in the dye molecules adsorption. The over-layered, large-sized ZnO particles enhance the light-harvesting by light scattering effect. Compared to the other mixtures of ZnO films, there is a decrease in the photovoltaic performance of the solar cell when ZnO particles (small and large in a ratio 1:1) were adsorbed onto the Ni (II) oxime complex, which are caused due to the decrease in the surface area and dye aggregation.

1. Introduction

The boom in technology development has led to a swift growth in the industrialization and urbanization which require a lot of energy for its sustenance. Currently, the developing and the underdeveloped nations are still dependent on the non-renewable source of energy which

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is limited. The overexploitation of these resources will lead to their depletion which takes several million years to recover. To conserve the non-renewable source of energy we need to opt for the renewable energy source. Among the renewable source of energy solar energy is an eco-friendly pioneer form. However, to absorb the solar light and heat and for converting and storing them in the form of energy we need solar cells. The triumph in the efficiency of power conversion has inspired and has brought much self-reliance in the knack of Dye-Sensitized Solar Cells (DSSCs). Developing of DSSCs having high efficiency will confront the high costs of commercially accessible solar cells which are based on sensitizers adhered to the metal oxide films (Grätzel, 2001; Habibzadeh et al., 2010; Jo et al., 2019; Nazeeruddin et al., 1993; O’Reagen & Gratzel, 1991; Park et al., 2019; Wen et al., 2019). However, in DSSCs, there is still substantial recombination of electrons and holes. These recombinations result from the thin coating of ZnO (6 µm) ensuing in the lessening of energy conversion and an increase in energy loss (Chappel et al., 2005). These recombinations are initiated predominately from the thinning of the ZnO layer onto ZnO nanocrystallite surface. Researchers have come forward and have evaluated this issue by raising the thickness of photo-electrode film for photovoltaic studies. A variety of techniques has been explored to succeed over the electron and hole recombination. One such method is the application of one-dimensional nanostructures that offer a direct corridor for electron transport or by developing composite materials/hybrid material along with semiconducting particle which boasts favourable energies. Besides, efforts have been made to curtail the recombination of electron and hole rate using core-shell structures with oxide coating (Chen et al., 2001; Kumara et al., 2003; Makhonina et al., 2019; Palomares et al., 2002; Sant & Kamat, 2002; Tennakone et al., 1999; Zhu et al., 2019). In DSSCs photons are brought together by the sensitizer, which is placed onto the plane of ZnO film. Consequently, in a DSSC the coefficient of the photoabsorption ability of the ZnO film along with the sensitizers is pretty lesser compared to the semiconductor film of a solar cell. In DSSCs the higher absorption coefficient from a ZnO film along with the sensitizers can be achieved by reducing its thickness required enough to uphold the increased concentration of photoelectrons. In the photo-absorbing layer, an increase in the concentration and lessening in the mass-transfer length of photoelectrons will significantly improve the photocurrent since the consequential reduction in the rear charge transfer from ZnO to the electrolyte solution. The rear charge transfer is an adverse phenomenon relating to their blending of photoelectrons in a semiconducting solar cell. Therefore, to enhance the photovoltaic conversion efficiency in a DSSC, the photoabsorption coefficient of the photo-absorbing layer has to be increased. Aside from this technique, a chain of methods has been demonstrated where the generation of photo-excited charge carriers are formed by coupling nanostructured films with optical effects (light scattering or optical confinement). This method is effective in enhancing the light-producing ability of photo-electrode film, and hence enhances the DSSC performance (Usami, 1997; Zhang et al., 2012). Furthermore, researchers have envisaged that admixing the large-sized TiO2 particles will drastically improve the optical absorption and optical path length of sensitizer anchored semiconducting metal oxide nanocrystalline films (Ferber & Luther, 1998; Lu et al., 2019; Rothenberger et al., 1999; Usami, 1999).

In recent years, researchers have proven that the efficiency of the scattering light mainly depends on the volume of scattering centres and the wavelength of incident light (Zhang et al., 2012). It was further deliberated that the light scattering attains its maximum value when the size of scattering centres is approximately or equal to ‘kλ’, where ‘k’ is a constant and ‘λ’ is the wavelength. Researchers have validated experimentally that the performance of DSSC can be enhanced considerably when the ZnO nanocrystalline films are in combination with large sized SiO2 or ZnO particles (Anderson & Bard, 1997; Barbe et al., 1997; Hore et al., 2005; Li et al., 2019; So et al., 2004). Investigations are also executed by making the
combination of photonic crystal layer with that of the conventional ZnO nanocrystalline films to enhance the scattering of light. This technique has resulted in enhancing the light-harvesting ability of the photo-electrode (Halaoui et al., 2005; Nishimura et al., 2003). On the other hand, combination/coupling of large-sized particles along with the nanocrystalline films has an inevitable effect by reducing the inner surface area of the photoelectrode film. This, in turn, results in neutralizing the augmentation effect of light scattering on the optical absorption, while the additional layer of photonic crystal on to ZnO nanocrystallite film results in an objectionable boost in the flow length of the electrons resulting in amplifying the recombination rate of photo-generated carriers. Attempts have been made to amplify the sensitizer adsorption into the ZnO film, by doping of nanoparticles such as Au, Ag etc., by increasing the nano-porosity and increasing the surface area (Dhas et al., 2011; Hjiri et al., 2019; Ihara et al., 2010; Muduli et al., 2012; Ni et al., 2006). However, one significant topic is that the injection arises from the aggregation of sensitizers in a nanocrystalline films. A lot of researchers have demonstrated that solar cell performance will also be reduced due to the aggregation of the sensitizer. In an aggregated sensitizers anchored on to the surface of semiconducting metal oxide films, not all sensitizers are in direct contact with the film and hence reduces the performance of the solar cell (Kambe et al., 2000; Wenger et al., 2005).

In general, for the researchers in the field of material engineering and chemical engineering, it is still an immense challenge to come up with a material having higher efficiency, except for cautious molecular engineering of panchromatic sensitizers having enhanced light-harvesting (especially in the near-infrared region) (Nazeeruddin & Grätzel, 2001; Nazeeruddin et al., 2001). Noteworthy, that in a DSSC adsorption of the sensitizer is a significant process which can alter/tune the solar cell performance. However, to date, the importance of the sensitizer adsorption and its effect on solar cell performance has not been thoroughly understood. It is well-accepted that in a DSSC, high-efficiency photo-electrode requires a high surface area for the loading of sufficient amounts of sensitizer molecules. Along with it the rapid electron transmission and deliberate electron recombination are the key factors in achieving higher efficiency (Nakade et al., 2003; Wang et al., 2020; Wang et al., 2006). Hence, more investigation has to recompense on the sensitizer’s adsorption onto the ZnO film, surface area, ability of light scattering and fast electron transport. In this article, we report on the novel Ni(II) (Q$_{1}$)$_{2}$ complex–adsorption onto ZnO film fabricated by the combination of small (∼25 nm) and large (∼200nm) ZnO nanoparticles. In the present article, instead of other metal-oxides, ZnO nanoparticles were used since ZnO is non-toxic and inexpensive.

2. Materials and Methods

2.1. Materials

Isatin (C$_{6}$H$_{5}$NO$_{2}$), Potassium hydroxide (KOH), dimethylglyoxime (C$_{4}$H$_{8}$N$_{2}$O$_{2}$), Hydrochloric acid (HCl), petroleum ether, ethanol, ZnO nanoparticles, terpineol, ethylcellulose and Indium-doped tin oxide (ITO) were supplied from Sigma-Aldrich. Distilled water was used throughout the experiment.

2.2. Instrumentation and Characterization

The working electrode was made-up using two different varieties of ZnO based on the size of the particle. Approximately 25 nm and 200 nm-sized ZnO nanoparticles were purchased from Sigma Aldrich. These two types of ZnO nanoparticles were used in the preparation of the film in four different ratios. The as-prepared film was further subjected to characterization. The surface morphologies of the samples were investigated using SEM (JSM-6710F, JEOL; Japan). The optical property of the film before and after deposition of sensitizer and the role of Ni(II)-(Q$_{1}$)$_{2}$ complex in the absorptions of light was studied using UV-vis spectroscopy.
(model UV-2550). The adsorption of Ni(II)-(Q1)2 complex on ZnO films were measured by ATR-IR spectrophotometer. The optical thickness of the instrument was measured by optical fibre instrument. Liquid chromatography coupled with mass spectrometry (LC-MS – model SHIMADZU 2010A) was used to observe the base peak. FT-IR (BRUKER desktop) was used to determine the functional group of the Ni(II)-(Q1)2 complex. The specific surface area of the samples was determined using Autosorb-1C (Quantachrome, USA) unit. 1H NMR was used to characterize the Ni(II)-(Q1)2 complex. The photocurrent-voltage characteristics of the DSSCs were measured under simulated solar illumination with a light intensity of 100 mW x cm⁻² (AM 1.5 G) using a sol 3A Class AAA Solar Simulator.

2.3. Synthesis of 2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4-carboxylic acid (Q1)

![Figure 1. Synthesis of 2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4-carboxylic acid](image)

In the synthesis of 2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4-carboxylic acid (Q1) (Figure 1), 1mmol of Isatin was added in 33% of KOH solution. To this reaction mixture 1.1mmol of dimethylglyoxime was added with continued stirring and refluxed for 6 hours. The completion of the reaction was determined by thin layer chromatography (TLC) technique. When the reaction is completed, the reaction mixture was cooled to room temperature. The obtained compound was acidified by adding 1N HCl dropwise until the pH of the solution reaches to 3. Precipitation of pale red coloured powder was noticed, which was further separated by filtration and washed with de-ionized water 2-3 times followed by pet-ether. The residual product obtained was further purified by silica gel chromatography (eluient-chloroform: methanol, 9:1 v/v) (Nicolini, 1996).

2.4. Synthesis of [2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4-carboxylic acid]2 Ni(II)] complex (Ni(II)-(Q1)2 complex)

![Figure 2. [2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4-carboxylic acid]2 Ni (II)] complex](image)

In the synthesis of [2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4-carboxylic acid]2 Ni (II)] complex (Figure 2), synthesized ligand (Q1) of 0.5 mmol was used as the starting material. Q1 was dissolved in 10 ml of ethanol. To this mixture, an equivalent quantity of metal salt solution in 20 ml ethanol (95%) was added dropwise with continued stirring. The solution was added until the brick-red precipitate was formed. Finally, the obtained precipitate was filtered, washed with de-ionized water followed by pet-ether and dried.

2.5. Preparation of ZnO films

Commercially available ZnO nanoparticles were used for the preparation of ZnO films. The films prepared were of different ratios between small and large particles. The ratios of ZnO
small: large particles are: 100:0, 90:10, 60:40 and 50:50. The samples were named as ZL0, ZL10, ZL40, and ZL50 where the numbers quantify the amount of larger ZnO particles in term of % present in the film. The processing of ZnO film of various ratios has a significant impact on the material properties. The properties include surface structure, porosity, optical light scattering, electron transport properties, and film roughness. All of these factors play a prominent role in determining the performance of photoanode (Kashyout et al., 2010; Lee et al., 2010; Liao et al., 2012; Suttiponparnit et al., 2011; Wang et al., 2004). Generally, the commercially available ZnO nanoparticles are aggregated, and hence these particles exhibit less performance when compared to the synthesized particles (Oçakoglu et al., 2008). To avoid aggregation of the ZnO particles, these ZnO particles were ground using the engineering built top planetary ball mill. The rotation speed of the agitator was set at 500 rpm and rotation time was set as 40 min under wet condition. Noteworthy, the planetary ball milling method will successfully reduce the particles aggregation leading to better dispersion stability. It should also be noted that to fabricate the effective DSSC the dispersion stability of ZnO nanoparticles should be in base fluid (Habibzadeh et al., 2010). Further, to have better dispersion, the ZnO particles of four different compositions were dispersed in ethanol solution and ultrasonicated for 40 min. This helps break the attractive van der Waals force among the ZnO particles at contact.

The ZnO paste was prepared using the ZnO nanoparticles (of various ratios of small: large particles) obtained after ultrasonication. Terpineol and ethyl cellulose were added to these ZnO nanoparticles and stirred using a magnetic stirrer for 48 h. Indium-doped tin oxide (ITO) glass substrates (Sigma Aldrich) having a sheet resistance of 8Ω/sq was ultrasonicated, cleaned using acetone, ethanol and distilled water for 15 minutes to ensure the complete removal of organic pollutants and other contamination. Doctor blade technique was employed for coating the complex paste of different ZnO nanoparticles onto the cleaned ITO glass substrate. Literature review states that, the highest efficiency was obtained when the thickness of ZnO film was restricted up to 14 to 15μm (Keis et al., 2002). In the present work, the ZnO film with approximately 5 μm thickness and 1×1 cm² of surface area was fabricated.

The obtained ZnO films were calcined at 450 °C for 1 h. After calcination, ZnO films were dipped in 0.3 mM solution of Ni(II) (Q1)₂ complex in presence of anhydrous ethanol for 24 h. After 24 h, the sensitizing molecules were completely absorbed by the film. ZnO electrodes impregnated with sensitizer of the various amount was assembled along with the earlier developed platinum counter electrodes. The electrolyte, KI, and I₂ (iodide-based redox electrolyte) were added into the cell via back filling through the injection hole on the counter electrode side.

Table 1.

<table>
<thead>
<tr>
<th>Samples</th>
<th>15 nm ZnO</th>
<th>200 nm ZnO</th>
<th>The thickness of the film</th>
<th>Coating method</th>
<th>Counter electrode</th>
</tr>
</thead>
<tbody>
<tr>
<td>ZL0</td>
<td>100</td>
<td>0</td>
<td>5μm</td>
<td>Doctor blade</td>
<td>Pt electrode</td>
</tr>
<tr>
<td>ZL10</td>
<td>90</td>
<td>10</td>
<td>5μm</td>
<td>Doctor blade</td>
<td>Pt electrode</td>
</tr>
<tr>
<td>ZL40</td>
<td>60</td>
<td>40</td>
<td>5μm</td>
<td>Doctor blade</td>
<td>Pt electrode</td>
</tr>
<tr>
<td>ZL50</td>
<td>50</td>
<td>50</td>
<td>5μm</td>
<td>Doctor blade</td>
<td>Pt electrode</td>
</tr>
</tbody>
</table>

3. Results and Discussion

3.1. ¹H NMR studies of Ni(II)-(Q1)₂ complexes

¹H NMR is an advanced technique where more than hundreds /thousands of resonance lines is obtained in the spectrum of a macromolecule which can be witnessed as individual peaks. It also provides the selectivity and the correlations between pairs of spins /groups of equivalent spins. It is also helpful in identifying the number of 1H-1H nuclear Overhauser
effects (NOEs). The $^1$H NMR analysis of the Ni(II)-(Q$_1$)$_2$ complexes sample was performed. Figure 3 corresponds to the $^1$H NMR spectrum of Ni(II)-(Q$_1$)$_2$ complexes acid sample. The as-prepared compound was purified by silica gel chromatography (eluent-chloroform: methanol, 9:1 v/v). In the $^1$H NMR spectra the function that corresponds to the particular δ ppm scale and their readings are given as follows: $^1$H NMR (DMSO-d$_6$, 400 MHz): The δ ppm scale at 13.9 corresponds to (s, 1H, COOH). Similarly, at 8.0 ppm is (d, 1H pyridine 3C–H), benzene at 7.6 ppm (d, 1H, Ar–H), 7.5 ppm (d, 1H, Ar–H), 7.1 ppm (t, 1H, Ar–H ) 6.9 ppm ( d, 1H, Ar-H), 11.4 ppm (s,1H, -N-OH ) and the aliphatic protons at 1.9 ppm (3H, s). From the Figure 3, it is clear that the $^1$H NMR spectrum of the material exhibited multiplet in the region 6.8-7.6 ppm. This region is assigned to the aromatic protons of the benzene ring present in the sample. A singlet at 7.9 ppm was observed, due to one proton which corresponds to the pyridine ring. Similarly, a singlet was observed at 1.9 ppm, which is considered as the three aliphatic protons of –CH$_3$ group. The peak in the region at 14 ppm represents the significant signal of a carboxylic proton (broad) (Issa et al., 2009; Kimtys & Balevicius, 1979; Nicolini, 1996).

$^1$H NMR spectrum of 2-[(1Z)-N-hydroxyethanimidoyl] quinoline-4- carboxylic acid.

3.2. The liquid chromatography-mass spectrum (LC-MS) studies of Ni(II)-(Q$_1$)$_2$ complexes

The mass spectrum was analyzed in LC-MS. The chromatogram obtained for the as-prepared sample is given in Figure 4a. The molecular ion peak of the fabricated compound shows [M+1]. The mass spectra obtained for the as-prepared sensitizer is given in Figure 4b. In Figure 4b, the molecular ions represent the base peaks in the spectra and hence, under electron impact, reflect their stable nature. The base peak of the obtained compound was m/z =231 (M+H).
3.3. FT-IR spectral studies of Ni(II)-(Q\textsubscript{1})\textsubscript{2} complexes

![FT-IR spectrum of Ni(II)-(Q\textsubscript{1})\textsubscript{2} complexes](image)

*Figure 5. FT-IR spectra of Ni(II)-(Q\textsubscript{1})\textsubscript{2} complexes*

The FT-IR spectrum of Ni(II)-(Q\textsubscript{1})\textsubscript{2} complexes recorded is given in Figure 5. The stretching bands in the region at 3381 cm\textsuperscript{-1}, 1735 cm\textsuperscript{-1}, 1616 cm\textsuperscript{-1}, and 945 cm\textsuperscript{-1} are assigned to (-OH), (-C=O), (-C=N) and (-N-O) stretching vibrations. After the development of Ni(II)-(Q\textsubscript{1})\textsubscript{2} complex, these stretching bands were shifted around 5 cm\textsuperscript{-1} due to the coordination of OH group of the oxime and nitrogen to the metal ion. The band at the region 945 cm\textsuperscript{-1} is attributed to the oxime N-O stretching of ligand, once the formation of the metal complex this band of N-O stretching has been shifted towards lower region confirming the co-ordination of the -OH group of the oxime to the metal ion. The intense band at 1735 cm\textsuperscript{-1} is ascribed to –C=O which indicates the occurrence of C=O group still after the development of the metal complex.

3.4. SEM studies of ZnO composite films

![SEM images of ZnO films](image)

*Figure 6. The surface sectional scanning electron microscope (SEM) images of the ZnO films prepared as the compositions of small and large ZnO nanoparticles*

The surface sectional SEM studies were performed to know the arrangement of the small and large ZnO nanoparticles on to the film. Figure 6a shows the regularly arranged small (∼25 nm) ZnO particle with the high surface area. Several hundreds of uniform nanoparticles were
observed. Some literature states that in DSSC the improvement of photovoltaic performance is governed by using small ZnO particle having high surface area and high mesoporous (Lee et al., 2012). However, it is believed that the contact area between the ZnO nanoparticles and ITO glass substrate, which is very high, helps in improving the efficiency of the cell (Yu et al., 2011). It is to be noted that the absorption of light by small ZnO particle is very less, and hence results in the decreased in photovoltaic efficiency. The reason behind this is the deficiency in the scattering effect caused by the small nanoparticles. Noteworthy, that the reflectance intensity mainly depends on both the scattering ability of the individual particles and the travelling path of the scattered light within the film (Nelson & Deng, 2008).

Researchers have suggested that the aforementioned issues in the DSSC and improving them can be done by introducing larger particles (Yu et al., 2011). In general, particles having higher specific surface area and larger porous film electrode favours the improvement of photoelectric conversion efficiency, since they possess more surface active sites. The presence of surface-active sites increases the adsorption of sensitizers and also in the ease moment of electrolyte through the interconnected porous networks. It also improvises the harvesting of light (Lee et al., 2012). Most of the reported literature reveals that the larger ZnO particles possess higher light–scattering ability than that of small nanoparticles. This intense scattering ability of large particles can be ascribed to at least two reasons. Firstly, the unique hollow structure of large particles is beneficial for light scattering. The increase in the light scattering within the hollow cavity increases the path length of the incident light, meanwhile the multi-reflection influences for the enhancement of scattering intensity (Kondo et al., 2008; Yu & Chen, 2008). Secondly the large particle semiconducting oxide films have possessed a void volume, which is beneficial to the improvement of light scattering (Nelson & Deng, 2008; Yu et al., 2011). These better physical properties of a large particle would show higher adsorption of sensitizer molecules and higher light scattering effect resulting in the enhancement of photovoltaic performance.

Based on the above findings, the larger particles were introduced along with the small ZnO particles. In Figure 6b, one can witness the fewer number of ZnO large particles mixed with ZnO small nanoparticles with the view of improving the light scattering ability and sensitizer adsorption. The pore size of the samples ZL10, ZL 40 and ZL 50 in Figure 6, have slightly changed to larger size depending on the added amount of larger particle, which would further improve the sensitizer’s adsorption into the film.

3.5. **UV-Visible absorbance spectral studies of ZnO composite films and sensitizer deposited ZnO composite**

![Graph a](image1)

![Graph b](image2)

*Figure 7.* The UV-visible absorbance spectrum of ZnO and c Ni(II)-(Q1)2 complexes formed films

The UV- vis spectral studies for the prepared samples were performed to know the ability of the film when exposed to light concerning the ratio of large and small ZnO particles. Figure 7,
corresponds to the UV light absorbance spectra of four different ZnO samples in the wavelength ranging from 300 to 800 nm. Figure 7, clearly confirms that there is no blue or redshift in the spectral absorbance on the incorporation of ZnO larger size particle with the small particle. However, it was observed that the UV light absorbance has increased gradually with increase in loading of ZnO particles of larger size. Further, the combination of small and large ZnO particles in the ratio 1:1 shows much absorption compared to other samples. The increase in the absorbance is due to the formation of hollow cavities between the particles, which might favour absorption and scattering of light. Meanwhile, the lowest light absorbance was achieved by the sample fabricated by using only the small ZnO particles. The lessening of light absorption might lead to poor photovoltaic efficiency. The increment of the light absorbance phenomena can be explained as a hollow cavity between large particles. The possible factors affecting the change in absorbance of four ZnO films with sensitizer sensitization were recorded. From Figure 7b, it is obvious that all ZnO films show a native absorption with comparable absorption intensity below 390 nm, which is caused by the ZnO semiconductor owing to the electron transfer from the valence band to the conduction band. However, the absorbance of the samples at wavelengths above 400 nm varies considerably; these absorbances are originated from the sensitizer molecules which are adsorbed on to the surface of ZnO and are linked to the film structure. Figure 7b also depicts that all the samples adorned by sensitizer consist of an absorption peak which is centred on 430 nm. This adsorption peak corresponds to the electronic coupling/ the heterojunction formed between the sensitizer and ZnO nanocrystalline films which will be evidence for a broad absorbance band and the shift towards the visible region. Furthermore, the absorption spectra specify that the sample ZL 50 bring on more effectual photon capturing in the visible region confirming the prolongation of strong light-scattering effect. This effect could somewhat scatter the incident light and deteriorates the transmittance of the films resulting in the simulated absorption deviating from the adsorbed sensitizer.

3.6. BET specific surface area studies of ZnO composite films

BET surface area studies for the representative samples were measured to know the specific surface area of the ZnO deposited on to the film. Figure 4 depicts the BET surface area of relatively different size mixture of ZnO particles. The BET specific surface areas were 50, 63, 71, and 85 m²g⁻¹ for the samples ZL0, ZL10, ZL 40 and ZL 50 respectively. It is evident from Figure 4 that the BET surface area of samples slightly increased with the increasing the quantity/number of larger ZnO particles. The results obtained are in agreement with the UV
data suggesting that the presence of these pores will be beneficial in the harvesting of light which in turn will enhance the efficiency of the material.

3.7. ATR-IR spectral bands of Ni(II)-(Q1)2 sensitizer adsorbed on ZnO films and free Ni(II)-(Q1)2 complex

The characteristics of the molecular species adsorbed on the substrate can be determined by the infrared spectra. Even the smaller shifts in the band position material can be observed. Upon this, deprotonation/surface coordination/any change in the symmetry of complexes leads to variation in the number and position of bands which can also be determined by IR studies.

![ATR-IR spectrum](image)

Figure 9. The ATR-IR spectrum of (a) Ni(II)-(Q1)2 complex and (b) Ni(II)-(Q1)2 complex adsorbed on ZL0 sample

Figure 9, shows that ATR-IR spectral bands of Ni(II)-(Q1)2 complex and Ni(II)-(Q1)2 sensitizer lies at 1728 cm\(^{-1}\) for the C=O stretching. The region at 1618 cm\(^{-1}\) is the asymmetric stretching of CO\(_2\). The band lying in the region 1332 cm\(^{-1}\) is assigned to symmetric stretching of CO\(_2\). The band 1147 cm\(^{-1}\) corresponds to the (–C-O-H) bending and 1201 cm\(^{-1}\) corresponds to single bond (-C-O) stretching. In the present work both -C=O and –CO\(_2\) stretching bands were observed confirming that both protonated and deprotonated carboxylic groups are there in the Ni(II)-(Q1)2 sample. The IR spectra of Ni(II)-(Q1)2 complex adsorbed on ZnO films showed a complete reduction in the relative intensity when ZnO adsorbed, which is due to (ν(C=O)). This further leads to a conclusion that the Ni(II)-(Q1)2 complex was put together through bidentate coordination(BC), instead of monodentate coordination (MC) [48]. The band at 1143 cm\(^{-1}\) which is assigned to (ν(-C-O-H)) was also absent upon adsorbing on ZnO, which further validate the bidentate surface complex formation at the surface.

3.8 Photovoltaic Studies

The as-prepared films were subjected to photovoltaic studies by measuring current-voltage performance irradiated by modified AM 1.5 sunlight with a power density of 100 mW/cm\(^2\) which is given in Figure 10. The overall detail of the photovoltaic studies such as current density versus voltage curves, The short circuit photocurrents (Jsc), open-circuit photovoltages (Voc); fill factors (FF), and the energy conversion efficiencies (η) for the four samples are summarized in Table 2. From the results, Jsc values of sample ZL0, ZL10, ZL40, and ZL 50 were deliberated as 0.92 mA*cm\(^{-2}\), 1.0 mA*cm\(^{-2}\), 1.18 mA*cm\(^{-2}\), and 1.23 mA*cm\(^{-2}\). We noticed that by increasing the part of larger particles the Jsc values were
increased. The enhancement is based on the adsorbed amount of sensitizer molecules and having strong light scattering ability into the films from the higher hollow cavity having a larger pore size (Yu et al., 2011). The Voc and FF values of sample’s ZL0, ZL10, ZL40, and ZL 50 were measured as 0.47 V, 0.446 V, 0.42 V, 0.38 V and 29, 28.3, 26.5, 25.9, respectively. According to our observation, both the Voc and FF values decreased with increasing the concentration of large particles. The decrease in these values is due to a decrease in the specific surface area resulting in the poor contact area between the ZnO particles and ITO glass substrate.

Most of the literature states that the enhanced electrochemical activity can be achieved by increasing the surface area of nanoparticles. In ZL0 sample, a similar signal of the photocurrent-voltage was observed. This might be due to (i) high surface area, (ii) good contact area and (iii) high mesoporous structure. The increase surface area and the good contact area of the electrode may encourage the reaction of I\(^{-3}\) reduction at the boundary between the particle and the electrolyte which improvises the FF. Furthermore, higher electrochemical activity produces higher Voc values. The greater mesoporous structures of ZnO electrode was produced due to the involvement of small nanoparticles by increasing the electron charge transfer. Meanwhile, as the mesoporous structures increases in a ZnO electrode, the electron charge transfer increases which enhance the electrochemical activity of the ZnO, resulting in higher Voc values and lower Jsc values (0.92 mA*cm\(^{-2}\)) for ZL0 sample when compared with other samples. This results in less efficiency (0.12%), which is comparatively less than that of the other solar cells. The lesser Jsc value is a cause of fewer depositions of sensitizer molecules and deprived light scattering ability. However, in sample ZL10 the Jsc values increases to 1.0 mA* cm\(^{-2}\) which might be due to faintly increase in the sensitizer molecule adsorption when compared to the sample ZL0 sample with an insignificant decrease in the Voc and FF values from 0.47V to 0.446 since the decrease in surface area and mesoporous structure. Consequently, on the whole, the photovoltaic efficiency is 0.126 %, which is higher than that of sample ZL0. Further, the sample ZL40 exhibits a higher photovoltaic efficiency of 0.132 %, which is also comparatively higher than that of the ZL0 sample. Even the Voc and FF values of ZL40 slightly decreased to 0.42 V and 26.5. Similarly, the Voc and FF values further decrease, and the Jsc value (1.18 mA *cm\(^{-2}\) ) was strongly increased compared to both sample ZL0 and ZL10 caused by the excessive sensitizer adsorption and strong light scattering ability into the film. However, when the sample ZL50 was used there was a decrease in the performance of the photovoltaic cell (0.123) when compared to ZL40. Hence, our result leads to the conclusion that the proportion used for the ZL40 sample is as an optimal incorporation ratio of small and large ZnO particles to improve the photovoltaic performance of DSSC.

![Figure 10. Current-voltage curves (Jsc-V) for the ZL0, ZL10, ZL40 and ZL50 samples.](image-url)
Interestingly, the Jsc value of (1.23 mA cm\(^{-2}\)) sample ZL50 was still increased due to more sensitizer adsorption and stronger light scattering ability than that of ZL40. According to Table 3, even though there is an increase in the Jsc value, the Voc (0.38 V) and FF (25.9) values have decreased, which in turn decreases the photovoltaic efficiency. The decrease in the photovoltaic efficiency based on the values of Voc and FF could be explained concerning the large surface area and poor contact area. The unusual development of the large surface area having the poor contact area between the ZnO particles and ITO glass substrate is the main reason for the decrease in the photovoltaic efficiency. There are some more possible reasons for the decrease in the photovoltaic effect which might be connected with the aggregation of sensitizers onto the surface of the film (Katoh et al., 2002). Notably, the solar cell performance depends on the load of the sensitizer, the higher the sensitizer load, the lesser the performance (Kambe et al., 2000; Wenger et al., 2005). The above studies lead to the conclusion that the incorporation of ZnO particles of various, by optimizing the proportion within one film electrode will possibly lead to better photovoltaic conversion efficiency.

Table 2.

Table: Values Showing the Open-Circuit Voltage, Short-Circuit Current Density, and Overall Light Conversion Efficiency for different sized, different composition of ZnO Film Electrodes Sensitized by Ni(II)-(Q\(_1\))\(_2\) complex.

<table>
<thead>
<tr>
<th>Samples</th>
<th>Voc(V)</th>
<th>Jsc(mA cm(^{-2}))</th>
<th>FF</th>
<th>η (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Sample a</td>
<td>0.47</td>
<td>0.92</td>
<td>29</td>
<td>0.12</td>
</tr>
<tr>
<td>Sample b</td>
<td>0.446</td>
<td>1.0</td>
<td>28.3</td>
<td>0.126</td>
</tr>
<tr>
<td>Sample c</td>
<td>0.42</td>
<td>1.18</td>
<td>26.5</td>
<td>0.132</td>
</tr>
<tr>
<td>Sample d</td>
<td>0.38</td>
<td>1.23</td>
<td>26.1</td>
<td>0.123</td>
</tr>
</tbody>
</table>

Based on our overall study, we can conclude that the light scattering ability ZL0 sample is less compared to that of ZL10 sample which is caused due to the larger pore size. However, the enhancement in the photovoltaic efficiency is not too high using ZL10 sample. When 10% of the larger particles were incorporated, a few hollow cavities were formed which was later filled by smaller ZnO particles, which leads to the lower light scattering ability, which is in agreement with the Figure 6b. This retards the optical beam of light passing through the ITO glass substrate and contact with the ZnO film.

The case of ZL40 samples, the ZnO film has more voids and pore size when compared to that of ZL10, Figure 6C. The incorporation of 40% ZnO larger nanoparticles leads to the increases in the pore size and hollow cavities in the films. These hollow cavities and the pores are partially filled by the small ZnO particles. The smaller ZnO nanoparticles, which can occupy some portion the hollow cavities form the intimate contact area between the particles and ITO glass substrate. Hence, the light scattering ability of ZL40 is higher than ZL0 and ZL10 caused by the variation in the ratio of large to smaller particle (Wang et al., 2006; Yu et al., 2011). Generally, when an optical beam is passed through the ITO glass and contact is made with the ZnO film electrodes, there are possibilities that the incident photon light gets reflected, scattered and transmitted within the film electrode. A part of incident light scattered within a ZnO films is returned to the surface is considered to be diffused reflectance (Lee et al., 2012). Noteworthy, that measuring the diffused reflectance spectrum is very essential to reveal the light scattering ability of samples. Based on the above two reasons largely sized ZnO nanoparticles are mixed for the enhancement of light scattering ability. Figure 6d shows a large number of hollow cavities with greater pore size is present in ZL50 sample. The larger pore size of ZL50 sample enhances the light scattering ability and sensitizer adsorption into the ZnO film. This leads to a better conversion efficiency of cells (Kondo et al., 2008; Lee et al., 2012; Nelson & Deng, 2008; Yu et al., 2010; Yu et al., 2011; Yu & Chen, 2008).
However, the specific surface area of film decreases because of the increasing number of large-sized ZnO particles. Even the contact area between the particles and ITO glass substrate was very poor. This is for the reason that the small ZnO particles were not sufficient enough to fill the number of hollow cavities. Normally, the decrease in a specific surface area with the poor contact area of the films retards the electron collection efficiency of ITO glass substrate thereby leading to poor performance. Further, it is experiential that large pore size and high porosity enhances the absorption of solar light and adsorption of sensitizer molecules into the ZnO film. However, ZL50 sample showed a very poor bonding with the ITO glass substrate. The poor bonding of particles with the ITO glass substrate decreases the electron collection efficiency of ITO glass substrate leading to poor photovoltaic performance (Nazeeruddin et al., 1993).

4. Conclusions
The synthesis of quinoline carboxylic acid oxime complex was carried out successfully. The adsorption of sensitizer onto the ZnO film slightly increases the photocurrent. The photocurrent increases due to the consequent decrease in the backward charge transfer from the ZnO to the electrolyte solution. A schematic illustration of Ni(II)-(Q1)2 complex adsorptions on different composition of small and large ZnO nanoparticles were performed. Our study reveals that the adsorption of the complex on ZnO films having only small pore sized particles show a less amount of photocurrent. The perfect combination of small and large ZnO nanoparticles can freely and fully adsorb the sensitizer molecules, which will increase the photocurrent of DSSC. In the experimental sample, the composition of the sample ZL40 is the optimized composition to obtain higher efficiency than other samples. The possible reason is the bonding between the electrode layer and the ITO glass substrate exerts and specific surface area thereby enhancing the photovoltaic performance. All the fabricated samples when used as cells showed very less efficiency which is due to the thickness of ZnO films (<6 μm), and hence the complex was not able to absorb the wavelength above >600 nm. However, by increasing the thickness above 6 μm, good results can be achieved which can be further used as the source for conserving the energy.

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References


